

8A 3Quadrants TRIACs

Product Summary

Symbol	Value	Unit
$I_{T(RMS)}$	8	A
$V_{DRM} V_{RRM}$	600/800	V
V_{TM}	1.55	V

Features

With high ability to withstand the shock loading of large current, With high commutation performances, 3 quadrants products especially recommended for use on inductive load.

Application

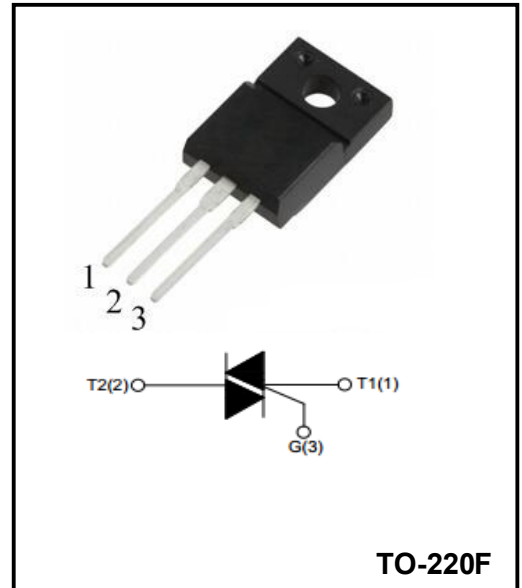
Washing machine, vacuums, massager, solid state relay, AC Motor speed regulation and so on.

Order Information

Part Number	Package	Marking	Packing	Packing Quantity
BTA08F	TO-220F	BTA08 600TW XXXX	box	1000PCS/box
BTA08F	TO-220F	BTA08 600SW XXXX	box	1000PCS/box
BTA08F	TO-220F	BTA08 600CW XXXX	box	1000PCS/box

Absolute maximum ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Repetitive peak off-state voltage	V_{DRM}	600/800	V
Repetitive peak reverse voltage	V_{RRM}	600/800	V
RMS on-state current	$I_{T(RMS)}$	8	A
Non repetitive surge peak on-state current (full cycle, F=50Hz)	I_{TSM}	80	A
I ² t value for fusing (tp=10ms)	I ² t	36	A ² s
Critical rate of rise of on-state current (IG = 2 x IG T)	di _r /dt	I - II - III 50	A/μs
Peak gate current	I _{GM}	4	A
Average gate power dissipation	P _G (AV)	1	W
Junction Temperature	T _J	-40~+125	°C
Storage Temperature	T _{STG}	-40 ~+150	°C



Electrical characteristics (TA=25°C, unless otherwise noted)

Parameter	Symbol	Test Condition	Value			Unit	
			TW	SW	CW		
Gate trigger current	I _{GT}	V _D =12V R _L =30Ω	I - II - III	≤5	≤10	≤35	mA
Gate trigger voltage	V _{GT}	T _J =25°C	I - II - III	≤1.3			V
Gate non-trigger voltage	V _{GD}	V _D =V _{DRM} , R _L =3.3kΩ, T _J =125°C		≥0.2			V
Holding current	I _H	I _T =100mA		≤10	≤15	≤35	mA
latching current	I _L	I _G =1.2I _{GT}	I - III	≤10	≤25	≤50	mA
			II	≤15	≤30	≤60	mA
Critical-rate of rise of commutation voltage	dV _D /dt	V _D =67%V _{DRM} , Gate Open T _J =125°C		≥20	≥40	≥400	V/μs

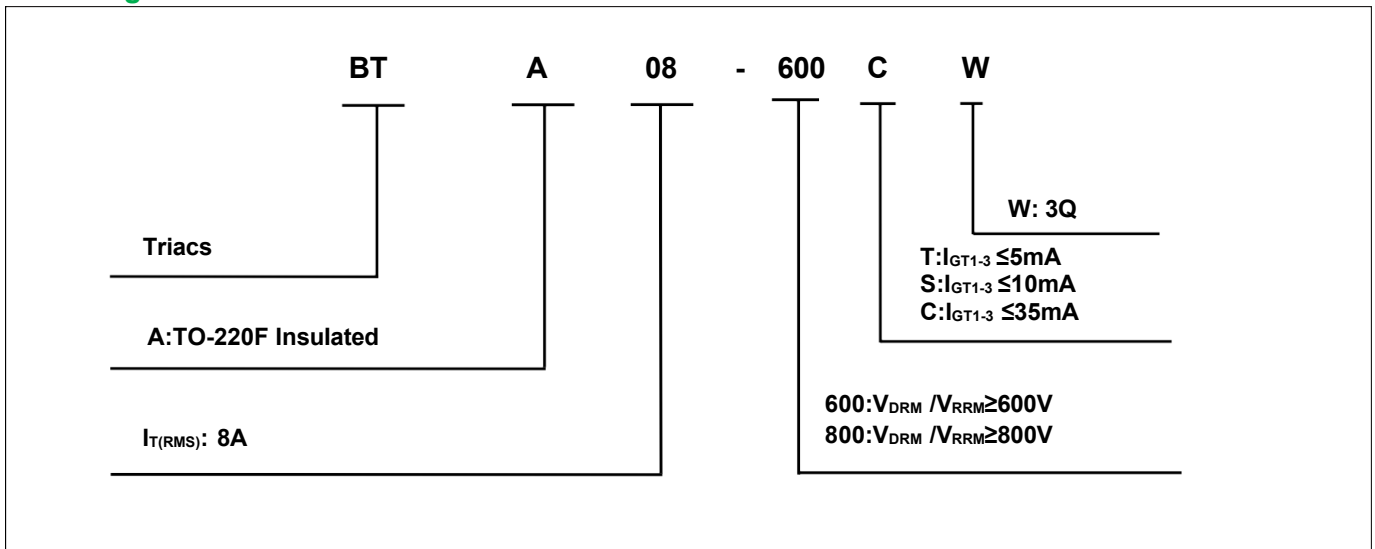
STATIC CHARACTERISTICS

Forward "on" voltage	V _{TM}	I _{TM} =11A tp=380μs		≤1.55			V
Repetitive Peak Off-State Current	I _{DRM}	V _D =V _{DRM} /V _{RRM}	T _J =25°C	≤10	≤10	≤10	μA
Repetitive Peak Reverse Current	I _{RRM}		T _J =125°C	≤1	≤1	≤1	mA

THERMAL RESISTANCES

Thermal resistance	R _{th(j-c)}	Junction to case(AC)		2.5			°C/W
	R _{th(j-a)}	Junction to ambient		60			°C/W

Ordering Information



Typical Characteristics

FIG.1: Maximum power dissipation versus RMS on-state current (full cycle)

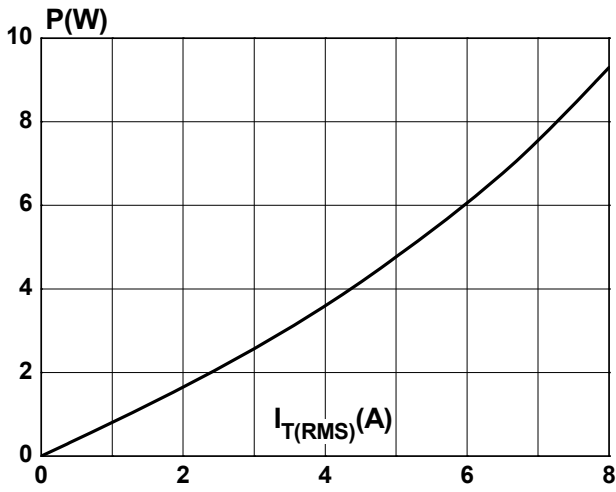


FIG.3: Surge peak on-state current versus number of cycles

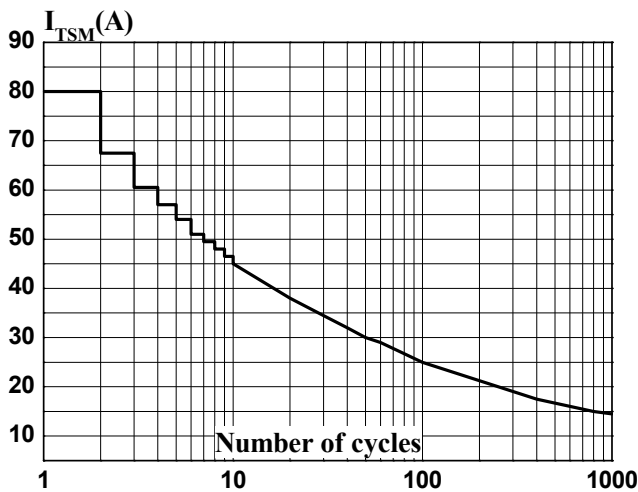


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ms}$

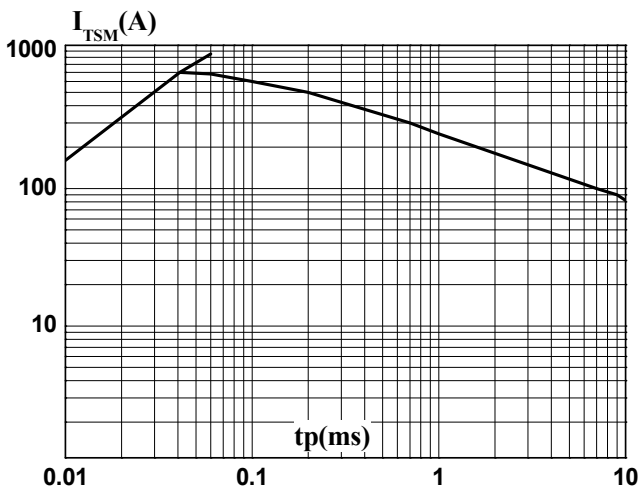


FIG.2: RMS on-state current versus case temperature (full cycle)

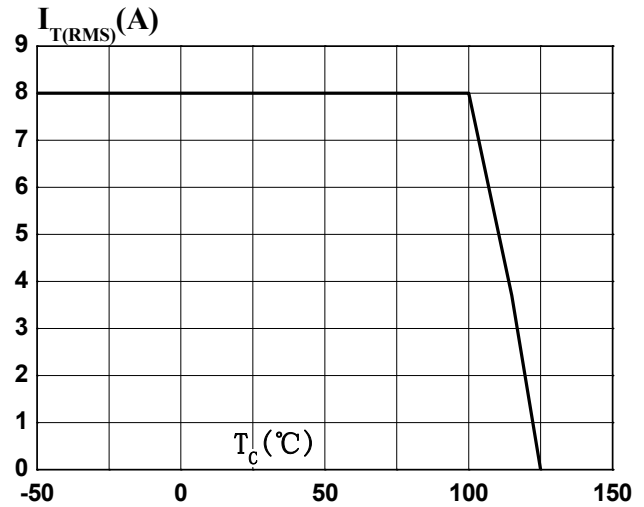


FIG.4: On-state characteristics (maximum values)

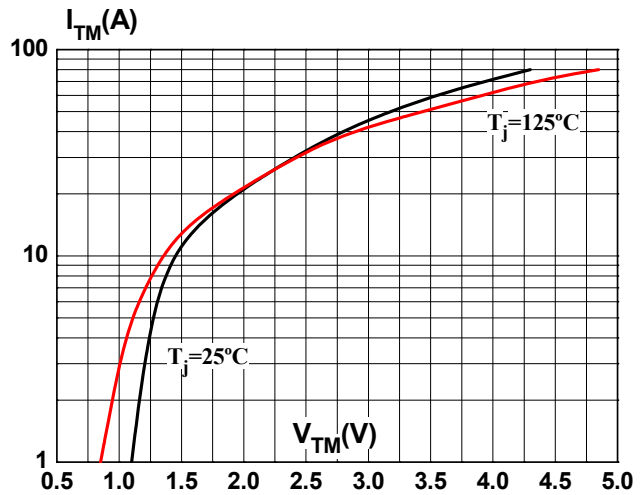
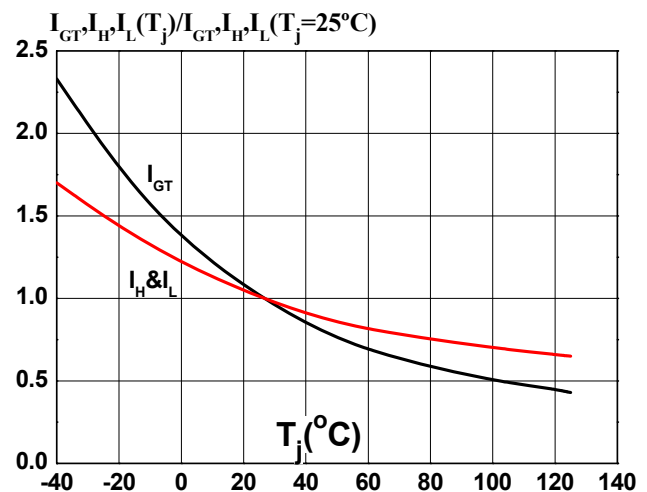
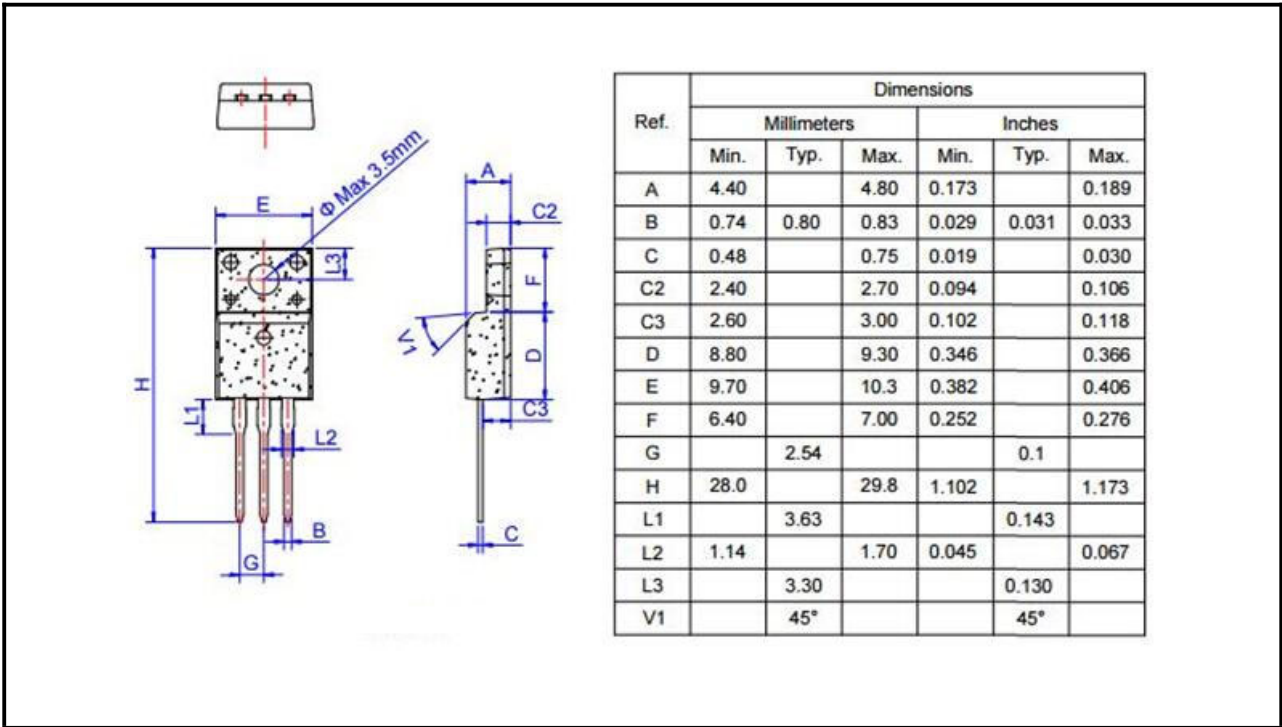


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction



Package Information

TO-220F



单击下面可查看定价，库存，交付和生命周期等信息

[>>YFW\(佑风微\)](#)